





60V PNP MEDIUM POWER TRANSISTOR IN E-LINE

Features

- BV_{CEO} > -60V
- I_C = -2A High Continuous Collector Current
- I_{CM} = -6A Peak Pulse Current
- T_J up to +200°C for High Temperature Operation
- Low Saturation Voltage < -0.3V @ -1A
- P_D = 1W Power dissipation
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

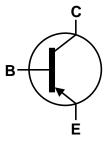
Mechanical Data

- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3:
- Weight: 0.159 grams (approximate)

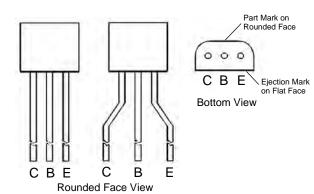








Device Symbol



Pin-Out Configuration

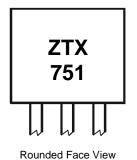
Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Case	Leads	Quantity
ZTX751	AEC-Q101	ZTX751	E-Line	Straight	4,000 loose in a Box
ZTX751STZ	AEC-Q101	ZTX751	E-Line	Joggled	2,000 taped per Ammo Box
ZTX751QSTZ	Automotive	ZTX751	E-Line	Joggled	2,000 taped per Ammo Box

Notes:

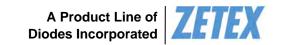
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZTX751 = Product type Marking Code





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-2	Α
Peak Pulse Current	I _{CM}	-6	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 6)	P _D	1.5	W	
Power Dissipation (Note 7)	P _D	1	W	
Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	116	°C/W	
Thermal Resistance Junction to Ambient (Note 7)	$R_{ heta JA}$	175	°C/W	
Thermal Resistance Junction to Lead (Note 8)	R _{θJL}	70	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +200	°C	

ESD Ratings (Note 9)

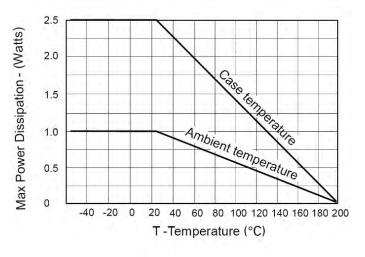
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

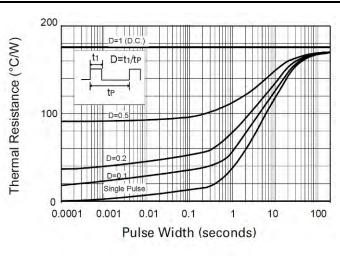
Notes:

- 6. For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
- 8. Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Derating curve

Safe Operating Area

Maximum transient thermal impedance





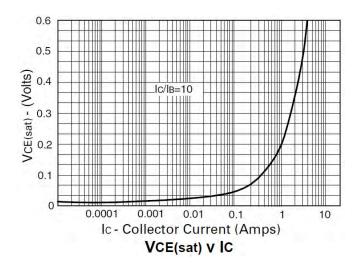
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

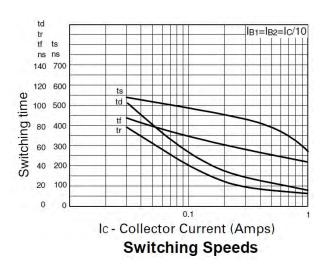
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	_	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-60	_	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	I _E = -100μA
Collector Cut-off Current	I _{CBO}	1	_	-0.1 -10	μA μA	$V_{CB} = -60V$ $V_{CB} = -60V, T_{amb} = +100$ °C
Emitter Cut-off Current	I _{EBO}	l	_	-0.1	μA	V _{EB} = -6V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}		-150 -280	-300 -500	mV	$I_C = -1A$, $I_B = -100mA$ $I_C = -2A$, $I_B = -200mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	l	-0.9	-1.25	V	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	l	-0.8	-1	V	$I_C = -1A$, $V_{CE} = -2V$
DC Current Gain (Note 10)	h _{FE}	70 100 80 40	200 200 170 80	- 300 - -	_	I_{C} = -50mA, V_{CE} = -2V I_{C} = -500mA, V_{CE} = -2V I_{C} = -1A, V_{CE} = -2V I_{C} = -2A, V_{CE} = -2V
Current Gain-Bandwidth Product (Note 10)	f _T	100	140		MHz	$V_{CE} = -5V, I_{C} = -100mA$ f = 100MHz
Output Capacitance (Note 10)	C _{obo}		_	30	pF	V _{CB} = -10V. f = 1MHz
Turn-On Times	ton		40	_	ns	$I_C = -500$ mA, $I_{B1} = I_{B2} = -50$ mA,
Turn-Off Times	toff	_	450	_	ns	V _{CC} = -10V

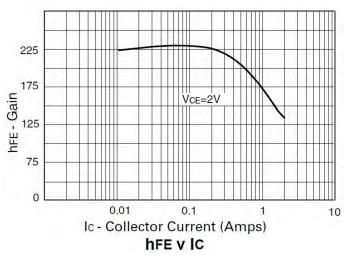
Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%

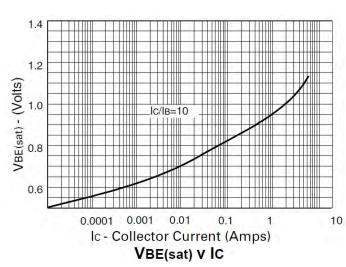


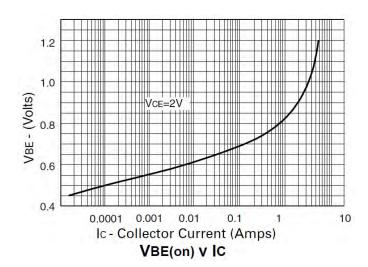
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









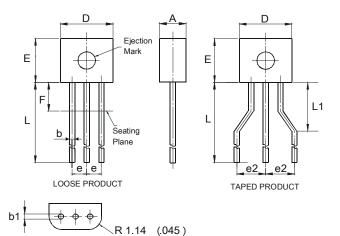






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



E-Line						
Dim	Min	Max	Тур			
Α	2.16	2.41	-			
b	0.41	0.495	_			
b1	0.41	0.495	-			
D	4.37	4.77	_			
Е	3.61	4.01	-			
е	_	_	1.27			
e2	_	_	2.54			
F	_	2.50	_			
L	13.00	13.97	_			
L1	2.50	3.50	-			
All	All Dimensions in mm					





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